NSN 5961-00-494-4963

Transistor - Page 1 of 2



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Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
15.0 collector to base voltage, dc and 12.0 collector to emitter voltage, dc and 4.5 emitter to base voltage, dc
Current Rating Per Characteristic:
10.00 milliamperes source cutoff current
Power Rating Per Characteristic:
0.36 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

NSN 5961-00-494-4963 Transistor - Page 2 of 2

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